Features

- Trench MV MOSFET Technology
- Voltage Controlled Small Signal Switch
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-Channel MOSFET

Maximum Ratings

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 357°C/W Junction to Ambient(Note 2)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	±20	V
Drain Current-Continuous	T_A=25°C	I_D	0.17	A
	T_A=100°C		0.11	
Drain Current-Pulsed(Note3)		I_{DM}	0.68	A
Power Dissipation(Note4)		P_D	0.35	W

Note:

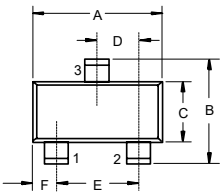
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

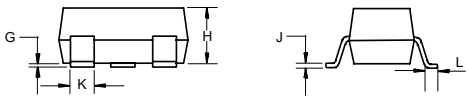
2.The value of RθJA is measured with the device mounted on the minimum recommend pad size, in the still air environment with TA =25℃.

3. Repetitive rating; pulse width limited by max. junction temperature.

4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

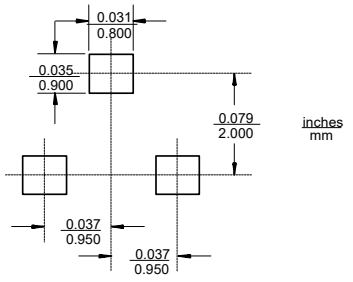
SOT-23



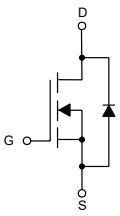


DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.110	0.120	2.80	3.04	
B	0.083	0.104	2.10	2.64	
C	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
E	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
H	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

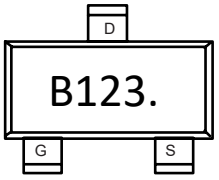
Solder Pad Layout



Internal Structure and Marking Code



1. GATE
2. SOURCE
3. DRAIN



ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS}=0V, I_D=250μA	100			V
Gate-Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250μA	1.0	1.7	2.8	V
Gate-Body Leakage Current	I_{GSS}	V_{GS}=± 20V, V_{DS}=0V			±50	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=100V, V_{GS}=0V			1	μA
		V_{DS}=20V, V_{GS}=0V			10	nA
Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=0.17A		2.5	6	Ω
		V_{GS}=4.5V, I_D=0.17A		2.7	10	
Forward Transconductance	g_{FS}	V_{DS}=5V, I_D=0.17A		450		mS
Gate Resistance	R_g	f=1 MHz, Open drain		6.0		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				0.17	A
Diode Forward Voltage	V_{SD}	V_{GS}=0V, I_S=0.34A			1.3	V
Reverse Recovery Time	t_{rr}	I_F=1A, dI_F/dt=100A/μs		20		ns
Reverse Recovery Charge	Q_{rr}			6.0		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	V_{DS}=25V,V_{GS}=0V,f=1MHz		35		pF
Output Capacitance	C_{oss}			2.5		
Reverse Transfer Capacitance	C_{rss}			1.6		
Total Gate Charge	Q_g	V_{DS}=50V,V_{GS}=10V,I_D=0.2A		1.6		nC
Gate-Source Charge	Q_{gs}			0.5		
Gate-Drain Charge	Q_{gd}			0.4		
Turn-On Delay Time	$t_{d(on)}$	V_{DD}=50V, V_{GS}=10V, R_{GEN}=3Ω, I_{DS}=1A		4		ns
Turn-On Rise Time	t_r			20		
Turn-Off Delay Time	$t_{d(off)}$			7		
Turn-Off Fall Time	t_f			31		

Curve Characteristics

Fig.1 - Typical Output Characteristics

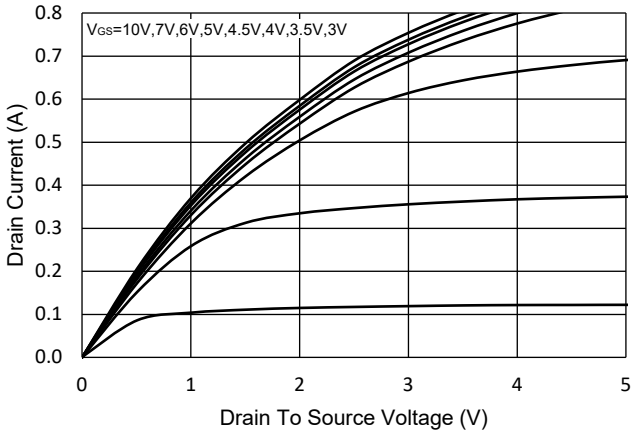


Fig.2 - Transfer Characteristic

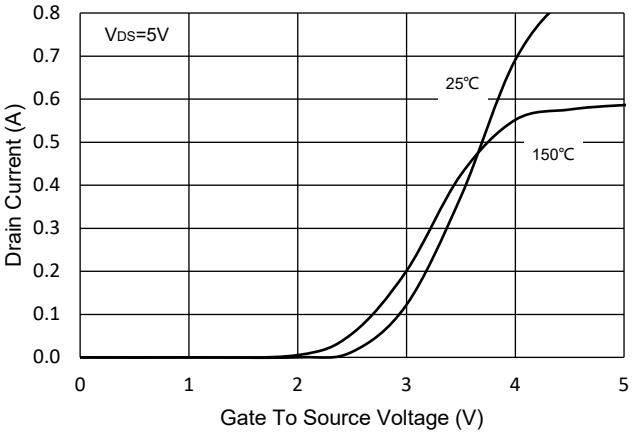


Fig. 3 - $R_{DS(ON)}$—V_{GS}

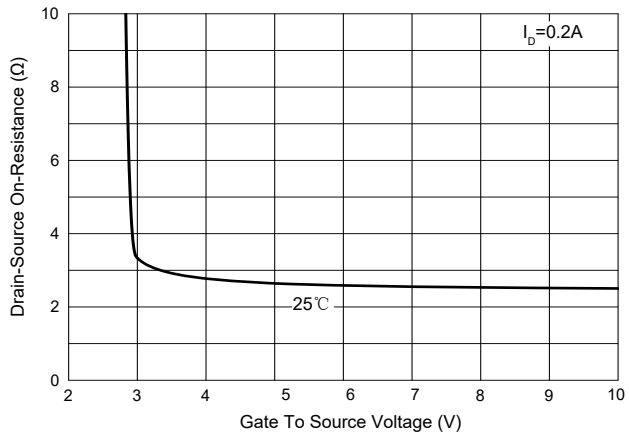


Fig.4 - $R_{DS(ON)}$ - I_D

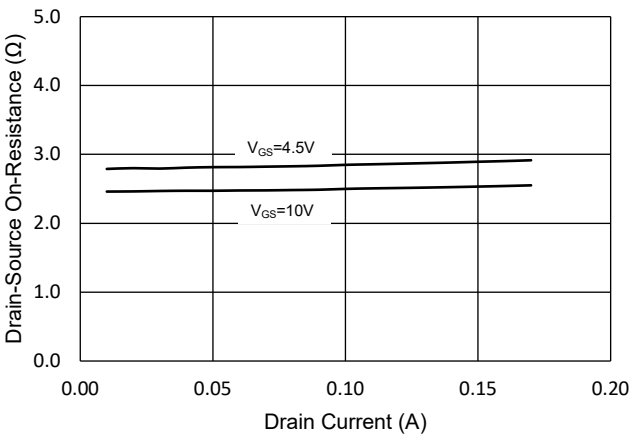


Fig. 5 - Capacitance Characteristics

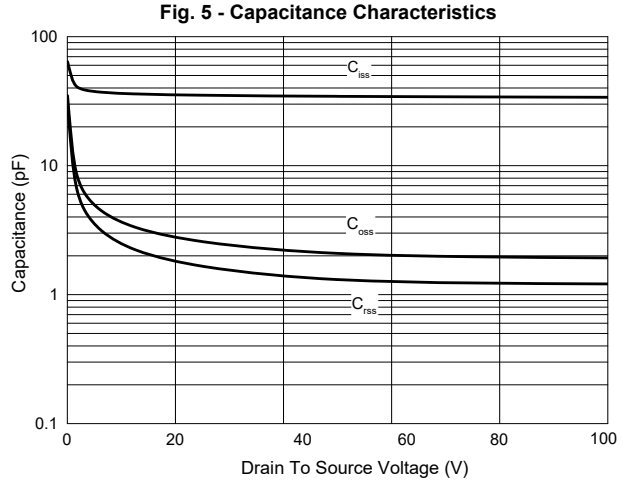
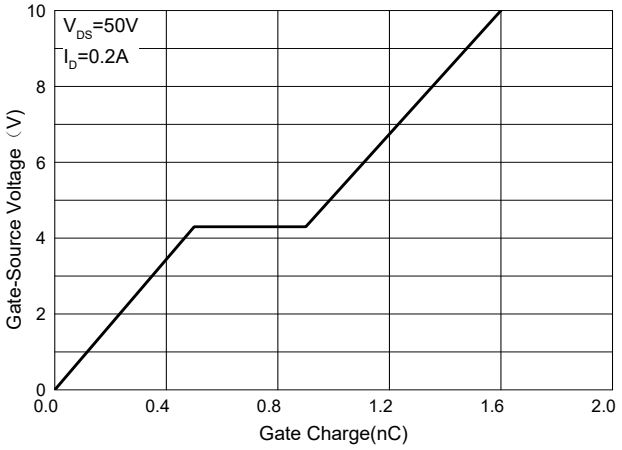


Fig. 6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

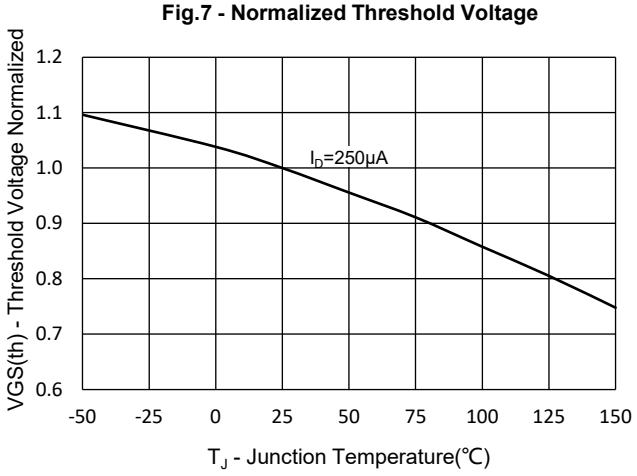


Fig.8 - Normalized On Resistance Characteristics

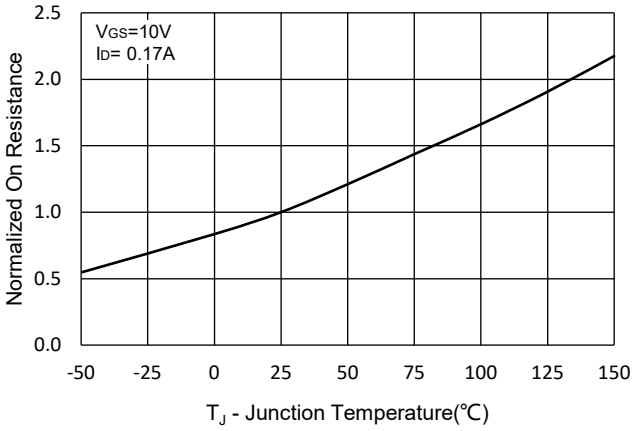


Fig.9 - I_S - V_{SD}

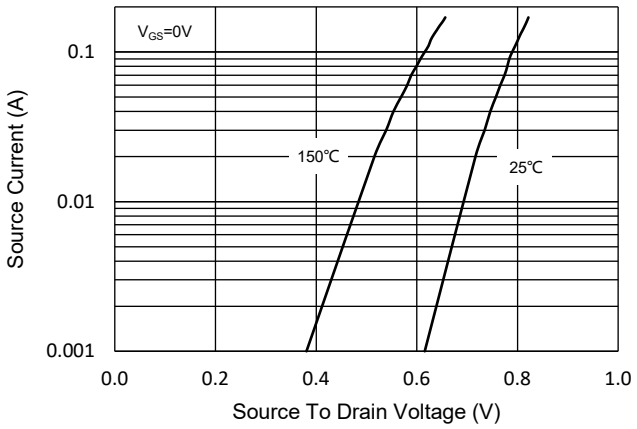


Fig. 10 - Drain Current

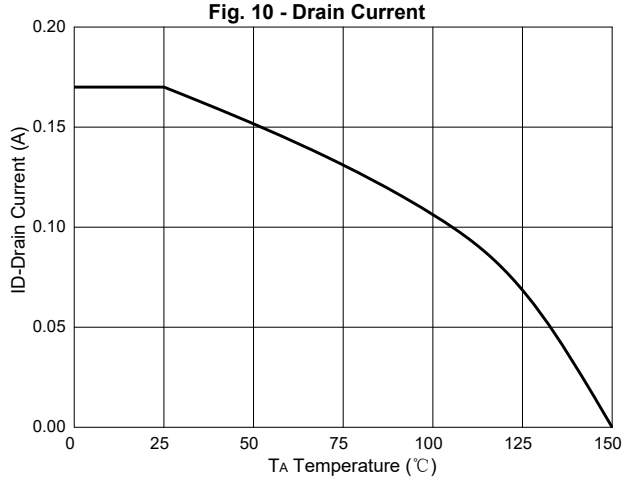
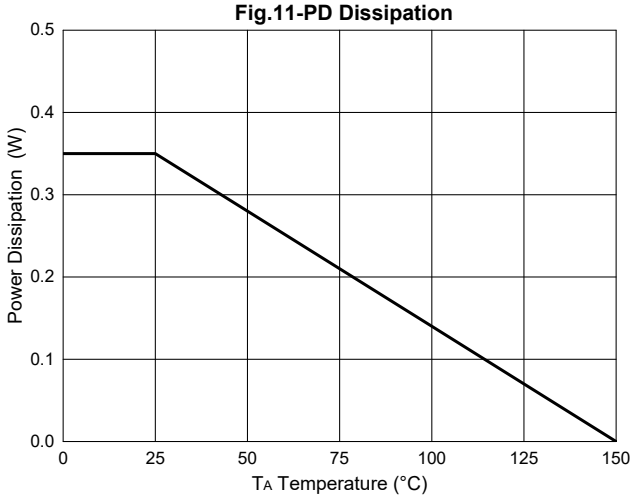


Fig.11-PD Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

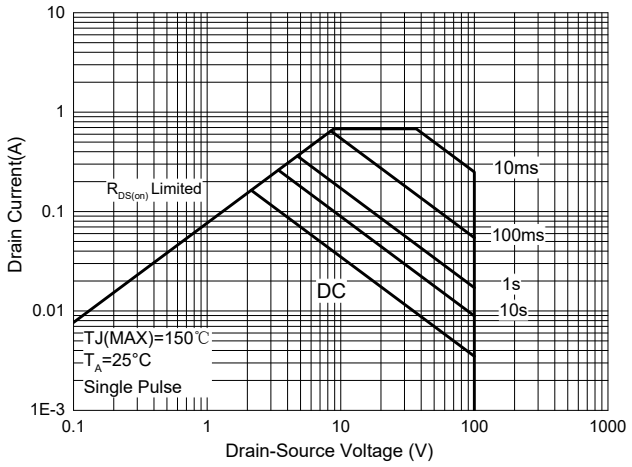
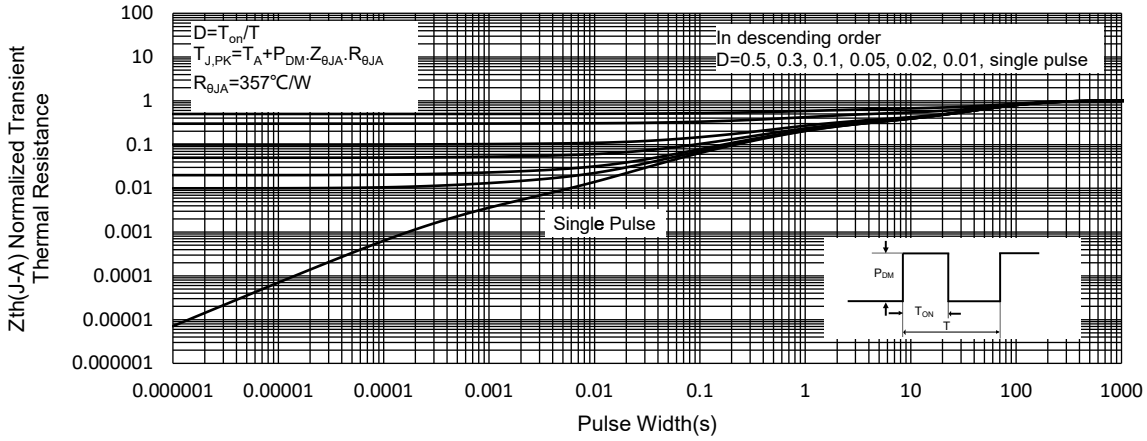


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel
Part Number-13P	Tape&Reel: 10Kpcs/Reel

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